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FlatPAK 5 x 6

1, 2 0 7, 8

3, 4 0 5, 6

LINKS TO ADDITIONAL RESOURCES

PRIMARY CHARACTERISTICS

I_{F(AV)}

 V_R

V_F at I_F

t_{rr (typ.)}

T_J max.

Package

Circuit configuration

30

3D Models



2 x 4 A

200 V

0.7 V

25 ns

175 °C

FlatPAK 5 x 6

Separated cathode

- 175 °C maximum operating junction temperature
- · Specific for output and snubber operation
- · Low forward voltage drop
- Low leakage current
- AEC-Q101 gualified
- Meets MSL level 1 per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in snubber, boost, piezo-injection, as high frequency rectifiers, and freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

MECHANICAL DATA

Case: FlatPAK 5 x 6

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002, meets JESD 201 class 2 whisker test

ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Peak repetitive reverse voltage		V _{RRM}		200	V			
Average restified forward current	per device	I	T _{Solderpad} = 170 °C, DC	- 8	A			
Average rectified forward current	per device	I _{F(AV)}	T _{Solderpad} = 169 °C, D = 0.5					
Non-repetitive peak surge current	per device	I _{FSM}	$T_J = 25 \text{ °C}, 10 \text{ ms}$ sinusoidal pulse	173				
Non-repetitive peak surge current	per diode			87				
Operating junction and storage temp	eratures	T _J , T _{Stg}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 $^{\circ}$ C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	200	-	-		
Forward voltage, per diode	V _F	$I_F = 4 A$	-	0.87	0.96	V	
		I _F = 4 A, T _J = 150 °C	-	0.7	0.78		
Reverse leakage current, per diode	I _R	$V_{R} = V_{R}$ rated	-	-	2		
		T _J = 150 °C, V _R = V _R rated	-	7	80	μA	
Junction capacitance	CT	V _R = 200 V	-	19	-	pF	

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
Reverse recovery time		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t =$	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}$		20	-		
	t _{rr}	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		-	-	25		
		T _J = 25 °C		-	17	-	A	
		T _J = 125 °C		-	29	-		
Pools recovery ourrent	I _{RRM}	T _J = 25 °C	I _F = 4 A dI _F /dt = 200 A/μs V _B = 160 V	-	2.1	-		
Peak recovery current		T _J = 125 °C		-	4	-		
	0	T _J = 25 °C		-	18	-		
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	60	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C		
Thermal resistance, junction to ambient, per diode	R _{thJA} ⁽¹⁾⁽²⁾		-	89	103	°C/W		
Thermal resistance, junction to mount, per diode	R _{thJM} ⁽³⁾		-	1.8	2.1	0/10		

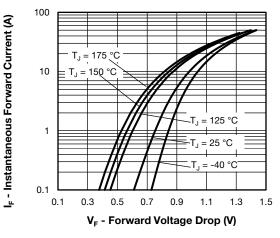
Notes

 $^{(1)}$ The heat generated must be less than the thermal conductivity from junction to ambient: $dP_D/dT_J < 1/R_{thJA}$

⁽²⁾ Free air, mounted or recommended copper pad area; thermal resistance R_{thJA} - junction to ambient

⁽³⁾ Mounted on infinite heatsink





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Fig. 1 - Typical Forward Voltage Drop Characteristics

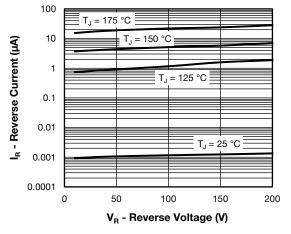


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

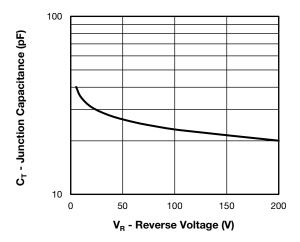


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

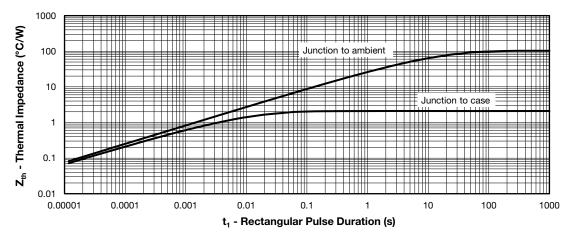
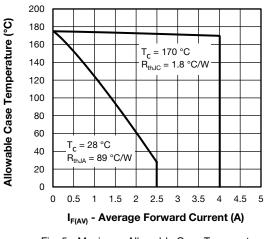


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

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Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

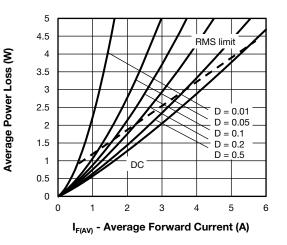


Fig. 6 - Forward Power Loss Characteristics

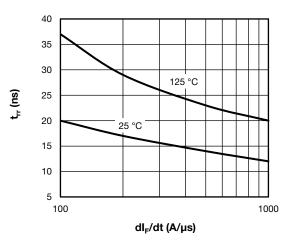


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

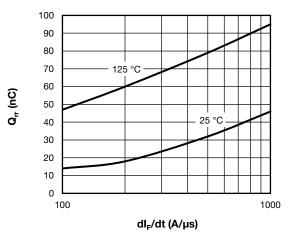


Fig. 8 - Typical Stored Charge vs. dl_F/dt

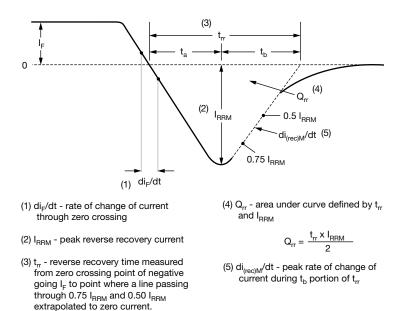
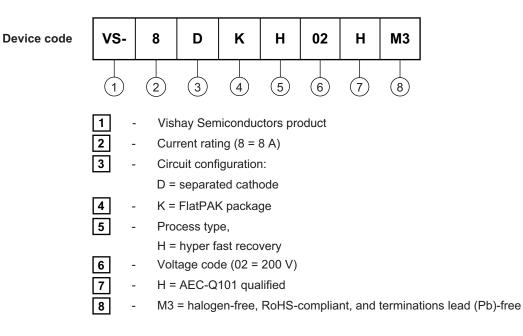


Fig. 9 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE



ORDERING INFORMATION (example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	PACKAGING DESCRIPTION			
VS-8DKH02HM3/H	0.10	н	1500	7"diameter plastic tape and reel			
VS-8DKH02HM3/I	0.10	I	6000	13" diameter plastic tape and reel			

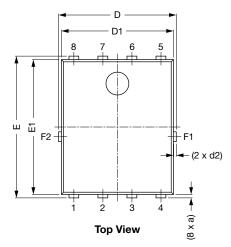
LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?96056					
Part marking information	www.vishay.com/doc?96059				
Packaging information	www.vishay.com/doc?88869				

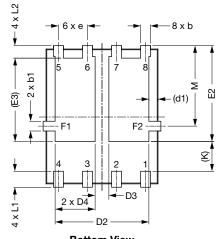




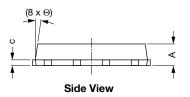
FlatPAK 5 x 6 (Dual)

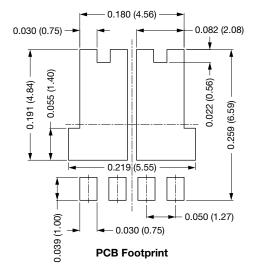
DIMENSIONS in inches (millimeters)











DIM		INCHES			MILLIMETERS	
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
А	0.035	0.039	0.043	0.89	0.99	1.09
(a)	-	0.006	-	-	0.15	-
b	0.013	0.017	0.020	0.32	0.43	0.52
b1	0.013	0.017	0.020	0.32	0.43	0.52
С	0.008	-	0.014	0.20	-	0.35
D	0.197	0.203	0.209	5.00	5.15	5.30
D1	0.189	0.193	0.197	4.80	4.90	5.00
D2	0.154	0.161	0.169	3.90	4.10	4.30
D3	0.020	0.024	0.031	0.50	0.60	0.80
D4	0.063	0.069	0.075	1.60	1.75	1.90
(d1)	-	0.016	-	-	0.40	-
(d2)	-	0.005	-	-	0.125	-
E	0.238	0.244	0.250	6.05	6.20	6.35

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1

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Outline Dimensions



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DIM.		INCHES		MILLIMETERS			
DIN.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
E1	0.228	0.232	0.236	5.80	5.90	6.00	
E2	0.157	0.165	0.173	4.00	4.20	4.40	
(E3)	-	0.144	-	-	3.65	-	
е		0.050 BSC		1.27 BSC			
(K)	0.039	-	-	1.00	-	-	
L1	0.019	-	0.043	0.48	-	1.10	
L2	0.012	-	0.031	0.30	-	0.80	
М	0.128	0.138	0.148	3.25	3.50	3.75	
Θ	0°	-	10°	0°	-	10°	

Notes

٠ Dimensioning and tolerancing per ASME Y14.5-2009

Dimensions D1 and E1 do not include mold flash or gate burrs ٠

Dimension (XX) means reference only ٠



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